

Title (en)

METHOD FOR APPLYING AN OVERGROWTH LAYER ONTO A SEED LAYER

Title (de)

VERFAHREN ZUR AUFBRINGUNG EINER ÜBERWUCHSSCHICHT AUF EINE KEIMSCHICHT

Title (fr)

PROCÉDÉ POUR APPLIQUER UNE COUCHE DE SURCROISSANCE SUR UNE COUCHE GERME

Publication

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Application

EP 15724285 A 20150521

Priority

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Abstract (en)

[origin: WO2016184523A1] The invention relates to a method for applying a masked overgrowth layer (14) onto a seed layer (2) for the production of semiconductor components, characterized in that a mask (6) for masking the overgrowth layer (14) is embossed on the seed layer (2).

IPC 8 full level

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Citation (search report)

See references of WO 2016184523A1

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